

DRD3770A52

Rectifier Diode

DS5988-1 January 2011 (LN28009)

FEATURES

- Double Side Cooling
- High Surge Capability

APPLICATIONS

- Rectification
- Free-wheel Diode
- DC Motor Control
- Power Supplies
- Welding
- Battery Chargers

VOLTAGE RATINGS

Part and Ordering Number	Repetitive Peak Voltages V _{DRM} and V _{DRM} V	Conditions
DRD3770A52 DRD3770A50 DRD3770A48 DRD3770A44	5200 5000 4800 4400	$V_{RSM} = V_{RRM} + 100V$

Lower voltage grades available.

ORDERING INFORMATION

When ordering, select the required part number shown in the Voltage Ratings selection table.

For example:

DRD3770A50 for a 5000V device

Note: Please use the complete part number when ordering and quote this number in any future correspondence relating to your order.

$\begin{array}{ll} \text{KEY PARAMETERS} \\ \text{V}_{\text{RRM}} & 5200 \text{V} \\ \text{I}_{\text{F(AV)}} & 3768 \text{A} \\ \text{I}_{\text{FSM}} & 70000 \text{A} \end{array}$

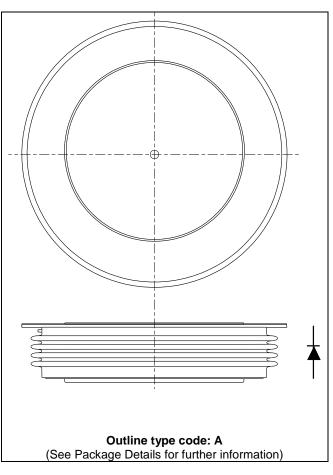


Fig. 1 Package outlines

CURRENT RATINGS

T_{case} = 75°C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units			
Double Si	Double Side Cooled						
$I_{F(AV)}$	Mean forward current	Half wave resistive load	4914	А			
I _{F(RMS)}	RMS value	-	7715	Α			
I _F	Continuous (direct) on-state current	-	7150	Α			
Single Side Cooled (Anode side)							
$I_{F(AV)}$	Mean forward current	Half wave resistive load	3213	Α			
$I_{F(RMS)}$	RMS value	-	5044	Α			
I _F	Continuous (direct) on-state current	-	4407	Α			

T_{case} = 100°C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units			
Double Si	Double Side Cooled						
$I_{F(AV)}$	Mean forward current	Half wave resistive load	3768	А			
I _{F(RMS)}	RMS value	-	5916	Α			
I _F	Continuous (direct) on-state current	-	5414	А			
Single Side Cooled (Anode side)							
I _{F(AV)}	Mean forward current	Half wave resistive load	2433	А			
I _{F(RMS)}	RMS value	-	3820	А			
I _F	Continuous (direct) on-state current	-	3256	А			

SURGE RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
I _{FSM}	Surge (non-repetitive) on-state current	10ms half sine, T _{case} = 150°C	56	kA
l ² t	I ² t for fusing	$V_R = 50\% V_{RRM} - \frac{1}{4}$ sine	15.8	MA ² s
I _{FSM}	Surge (non-repetitive) on-state current	10ms half sine, T _{case} = 150°C	70	kA
l ² t	I ² t for fusing	$V_R = 0$	24.5	MA ² s

THERMAL AND MECHANICAL RATINGS

Symbol	Parameter	Test Conditions		Min.	Max.	Units
R _{th(j-c)}	Thermal resistance – junction to case	Double side cooled	DC	-	0.0065	°C/W
		Single side cooled	Anode DC	-	0.013	°C/W
			Cathode DC	-	0.013	°C/W
R _{th(c-h)}	Thermal resistance – case to heatsink	Clamping force 83.0kN	Double side	-	0.001	°C/W
		(with mounting compound)	Single side		0.002	°C/W
T_{vj}	Virtual junction temperature	On-state (conducting)		ı	160	°C
		Reverse (blocking)		ı	150	°C
T_{stg}	Storage temperature range			-55	150	°C
Fm	Clamping force			75.0	91.0	kN

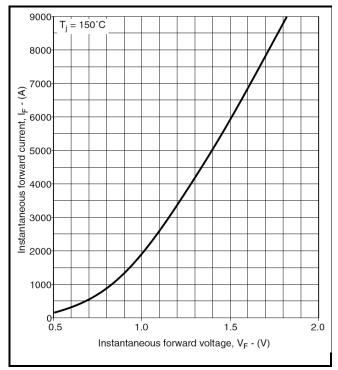
CHARACTERISTICS

Symbol	Parameter	Test Conditions	Min.	Max.	Units
V_{FM}	Forward voltage	At 3000A peak, T _{case} = 25°C	-	1.17	V
I _{RM}	Peak reverse current	At V _{DRM} , T _{case} = 150°C	-	200	mA
V _{TO}	Threshold voltage	At T _{vj} = 150°C	-	0.82	V
r _T	Slope resistance	At T _{vj} = 150°C	-	0.111	mΩ

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CURVES



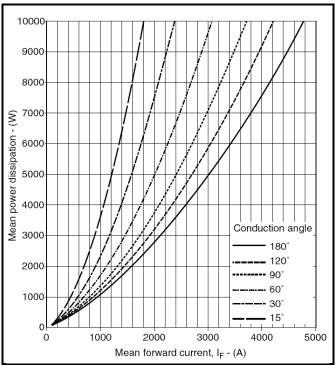


Fig.2 Maximum (limit) forward characteristics

Fig.3 Power loss curves - sine wave

V_{TM} EQUATION

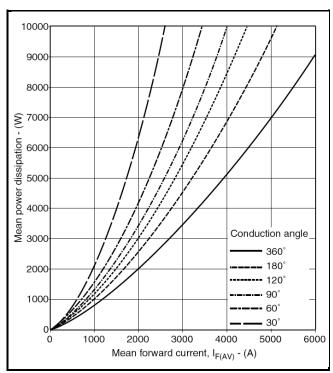
 $V_{TM} = A + Bln (I_T) + C.I_T + D.\sqrt{I_T}$

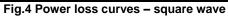
Where A = -0.0436

B = 0.10422 $C = 7.6 \times 10^{-5}$

D = 0.00243

these values are valid for $T_i = 150$ °C for $I_F 400$ A to 9000A





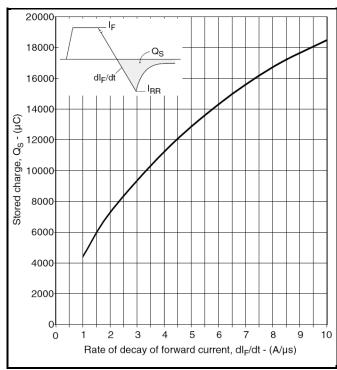
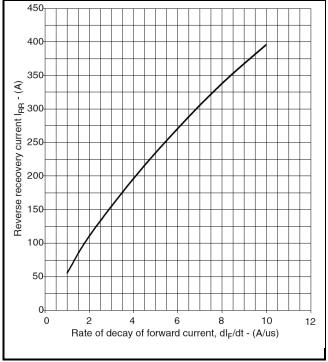


Fig.5 Stored charge



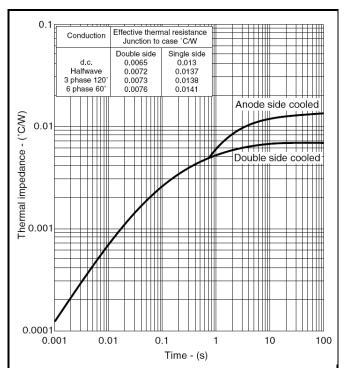


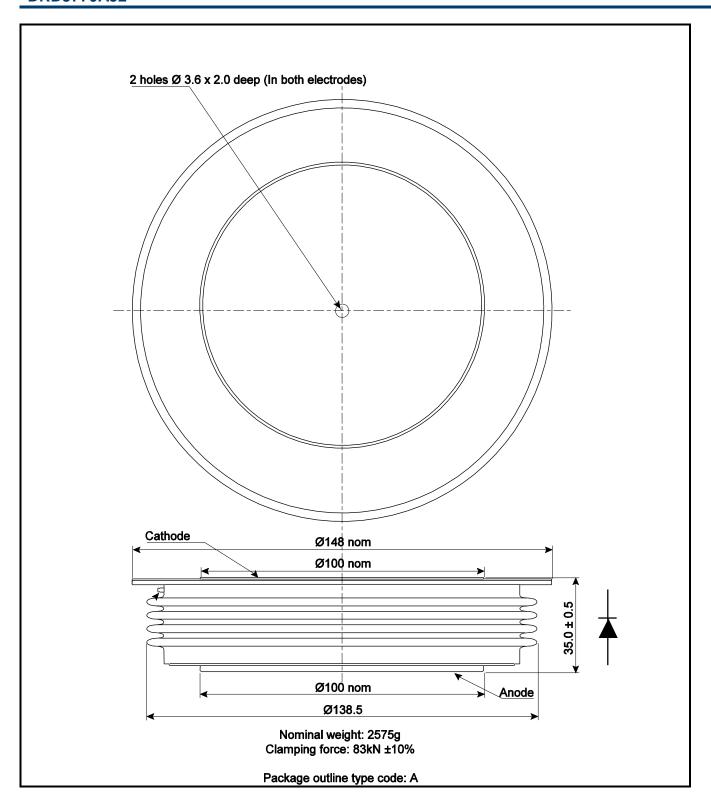
Fig.6 Reverse recovery current

Fig.7 Maximum (limit) transient thermal impedance – junction to case

PACKAGE DETAILS

For further package information, please contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.

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